

## FEATURES

Extreme high temperature operation up to 210°C

Latch-up proof

JESD78D Class II rating

Low leakage

Ultralow capacitance and charge injection

Source capacitance, off: 2.9 pF at  $\pm 15$  V dual supply

Drain capacitance, off: 34 pF at  $\pm 15$  V dual supply

Charge injection: 0.2 pC at  $\pm 15$  V dual supply and  
+12 V single supply

Low on resistance: 290  $\Omega$  typical for dual supply at 210°C

$\pm 9$  V to  $\pm 22$  V dual-supply operation

9 V to 40 V single-supply operation

48 V supply maximum rating

Fully specified at  $\pm 15$  V,  $\pm 20$  V, +12 V, and +36 V

$V_{SS}$  to  $V_{DD}$  analog signal range

## APPLICATIONS

Downhole drilling and instrumentation

Avionics

Heavy industrial

High temperature environments

## GENERAL DESCRIPTION

The **ADG5298** is a latch-up proof, monolithic, complementary metal-oxide semiconductor (CMOS) analog multiplexer designed for operation up to 210°C. The **ADG5298** switches one of eight inputs to a common output, as determined by the 3-bit binary address lines, A0, A1, and A2.

An EN input enables or disables the device. When EN is disabled, all channels switch off. The ultralow capacitance and charge injection of this switch makes it an ideal solution for data acquisition and sample-and-hold applications, where low glitch and fast settling are required.

The switch conducts equally well in both directions when on, and it has an input signal range that extends to the power supplies. In the off condition, signal levels up to the supplies are blocked.

This multiplexer is available in a 16-lead ceramic flat package (FLATPACK) and a 16-lead ceramic flat package with reverse formed gullwing leads (FLATPACK\_RF). Both packages are designed for robustness at extreme temperatures and are qualified for up to 1000 hours of operation at the maximum temperature rating.

The **ADG5298** is a member of a growing series of high temperature qualified products offered by Analog Devices, Inc. For a complete selection table of available high temperature products, see the high temperature product list and qualification data available at [www.analog.com/hightemp](http://www.analog.com/hightemp).

Rev. 0

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## FUNCTIONAL BLOCK DIAGRAM

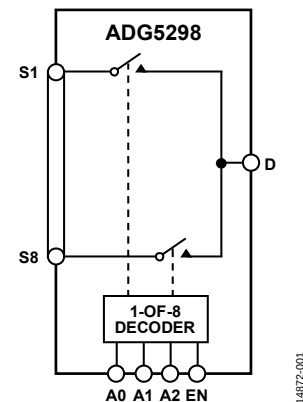


Figure 1.

## PRODUCT HIGHLIGHTS

1. Trench Isolation Guards Against Latch-Up and Minimizes Parasitic Leakage.  
A dielectric trench separates the P channel and N channel transistors to prevent latch-up even under severe overvoltage conditions.
2. Achieved JESD78D Class II rating.  
The **ADG5298** was stressed to  $\pm 500$  mA with a 10 ms pulse at the maximum temperature of the device (210°C).
3. 0.2 pC Charge Injection.
4. Dual-Supply Operation.  
For applications where the analog signal is bipolar, the **ADG5298** can operate from dual supplies of up to  $\pm 22$  V.
5. Single-Supply Operation.  
For applications where the analog signal is unipolar, the **ADG5298** can operate from a single rail power supply of up to 40 V.
6. 3 V Logic-Compatible Digital Inputs.  
 $V_{INH} = 2.0$  V,  $V_{INL} = 0.8$  V.
7. No Logic Power Supply ( $V_L$ ) Required.

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## REVISION HISTORY

9/2016—Revision 0: Initial Version

## SPECIFICATIONS

## ±15 V DUAL-SUPPLY

$V_{DD} = +15\text{ V} \pm 10\%$ ,  $V_{SS} = -15\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$ , and  $-55^{\circ}\text{C} \leq T_A \leq +210^{\circ}\text{C}$ , unless otherwise noted.

Table 1.

| Parameter                            | Symbol <sup>1</sup>                 | Test Conditions/Comments <sup>1</sup>                                                                                                                                                           | Min      | Typ <sup>2</sup> | Max      | Unit          |
|--------------------------------------|-------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------|------------------|----------|---------------|
| ANALOG SWITCH                        |                                     |                                                                                                                                                                                                 |          |                  |          |               |
| Analog Signal Range                  |                                     |                                                                                                                                                                                                 | $V_{SS}$ |                  | $V_{DD}$ | V             |
| On Resistance                        | $R_{ON}$                            | Supply voltage ( $V_S$ ) = $\pm 10\text{ V}$ , drain source current ( $I_{DS}$ ) = $-1\text{ mA}$ , see Figure 31; for maximum $R_{ON}$ , $V_{DD} = +13.5\text{ V}$ , $V_{SS} = -13.5\text{ V}$ |          | 290              | 400      | $\Omega$      |
| On-Resistance Match Between Channels | $\Delta R_{ON}$                     | $V_S = \pm 10\text{ V}$ , $I_{DS} = -1\text{ mA}$                                                                                                                                               |          | 2.0              | 10       | $\Omega$      |
| On-Resistance Flatness               | $R_{FLAT(ON)}$                      | $V_S = \pm 10\text{ V}$ , $I_{DS} = -1\text{ mA}$                                                                                                                                               |          | 60               | 130      | $\Omega$      |
| LEAKAGE CURRENTS                     |                                     |                                                                                                                                                                                                 |          |                  |          |               |
| Source Off Leakage                   | $I_S(\text{off})$                   | $V_{DD} = +16.5\text{ V}$ , $V_{SS} = -16.5\text{ V}$<br>$V_S = \pm 10\text{ V}$ , $V_D = \mp 10\text{ V}$ , see Figure 32                                                                      | -8       | $\pm 0.005$      | +8       | nA            |
| Drain Off Leakage                    | $I_D(\text{off})$                   | $V_S = \pm 10\text{ V}$ , $V_D = \mp 10\text{ V}$ , see Figure 32                                                                                                                               | -60      | $\pm 0.005$      | +60      | nA            |
| Channel On Leakage                   | $I_D(\text{on})$ , $I_S(\text{on})$ | $V_S = V_D = \pm 10\text{ V}$ , see Figure 30                                                                                                                                                   | -70      | $\pm 0.01$       | +70      | nA            |
| DIGITAL INPUTS                       |                                     |                                                                                                                                                                                                 |          |                  |          |               |
| Input High Voltage                   | $V_{INH}$                           |                                                                                                                                                                                                 | 2.0      |                  |          | V             |
| Input Low Voltage                    | $V_{INL}$                           |                                                                                                                                                                                                 |          |                  | 0.8      | V             |
| Input Current                        | $I_{INL}$ or $I_{INH}$              | Input voltage ( $V_{IN}$ ) = ground voltage ( $V_{GND}$ ) or $V_{DD}$                                                                                                                           | -0.1     | +0.002           | +0.1     | $\mu\text{A}$ |
| Digital Input Capacitance            | $C_{IN}$                            |                                                                                                                                                                                                 |          | 3                |          | pF            |
| DYNAMIC CHARACTERISTICS <sup>3</sup> |                                     |                                                                                                                                                                                                 |          |                  |          |               |
| Transition Time                      | $t_{\text{TRANSITION}}$             | Load resistance ( $R_L$ ) = $300\text{ }\Omega$ , load capacitance ( $C_L$ ) = $35\text{ pF}$ , $V_S = 10\text{ V}$ , see Figure 36                                                             |          | 150              | 335      | ns            |
| On Time                              | $t_{ON}(\text{EN})$                 | $R_L = 300\text{ }\Omega$ , $C_L = 35\text{ pF}$ , $V_S = 10\text{ V}$ , see Figure 38                                                                                                          |          | 125              | 275      | ns            |
| Off Time                             | $t_{OFF}(\text{EN})$                | $R_L = 300\text{ }\Omega$ , $C_L = 35\text{ pF}$ , $V_S = 10\text{ V}$ , see Figure 38                                                                                                          |          | 160              | 275      | ns            |
| Break-Before-Make Time Delay         | $t_D$                               | $R_L = 300\text{ }\Omega$ , $C_L = 35\text{ pF}$ , S1 voltage ( $V_{S1}$ ) = S2 voltage ( $V_{S2}$ ) = $10\text{ V}$ , see Figure 37                                                            | 25       | 55               |          | ns            |
| Charge Injection                     | $Q_{INJ}$                           | $V_S = 0\text{ V}$ , $R_S = 0\text{ }\Omega$ , $C_L = 1\text{ nF}$ , see Figure 39                                                                                                              |          | 0.2              |          | pC            |
| Off Isolation                        |                                     | $R_L = 50\text{ }\Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ , see Figure 34                                                                                                             |          | 86               |          | dB            |
| Channel to Channel Crosstalk         |                                     | $R_L = 50\text{ }\Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ , see Figure 33                                                                                                             |          | -80              |          | dB            |
| -3 dB Bandwidth                      |                                     | $R_L = 50\text{ }\Omega$ , $C_L = 5\text{ pF}$ , see Figure 35                                                                                                                                  |          | 110              |          | MHz           |
| Source Capacitance, Off              | $C_S(\text{off})$                   | $V_S = 0\text{ V}$ , frequency ( $f$ ) = $1\text{ MHz}$                                                                                                                                         |          | 2.9              |          | pF            |
| Drain Capacitance, Off               | $C_D(\text{off})$                   | $V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                                                                                         |          | 34               |          | pF            |
| Source/Drain Capacitance, On         | $C_D(\text{on})$ , $C_S(\text{on})$ | $V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                                                                                         |          | 37               |          | pF            |
| POWER REQUIREMENTS                   |                                     |                                                                                                                                                                                                 |          |                  |          |               |
| Supply Current                       |                                     | $V_{DD} = +16.5\text{ V}$ , $V_{SS} = -16.5\text{ V}$                                                                                                                                           |          |                  |          |               |
| Positive                             | $I_{DD}$                            | Digital inputs = $0\text{ V}$ or $5\text{ V}$ , see Figure 28                                                                                                                                   |          | 60               | 80       | $\mu\text{A}$ |
| Negative                             | $I_{SS}$                            | Digital inputs = $0\text{ V}$ or $5\text{ V}$ , see Figure 29                                                                                                                                   |          | 10               | 20       | $\mu\text{A}$ |
| Ground Current                       | $I_{GND}$                           | Digital inputs = $0\text{ V}$ or $5\text{ V}$                                                                                                                                                   |          | 60               | 80       | $\mu\text{A}$ |
| Supply Range                         | $V_{DD}/V_{SS}$                     | $GND = 0\text{ V}$                                                                                                                                                                              | $\pm 9$  |                  | $\pm 22$ | V             |

<sup>1</sup> See the Terminology section.

<sup>2</sup>  $T_A = 25^{\circ}\text{C}$ , except for the analog switch and power requirements values, where  $T_A = 210^{\circ}\text{C}$ .

<sup>3</sup> Guaranteed by design, not subject to production test.

**±20 V DUAL SUPPLY**

$V_{DD} = +20\text{ V} \pm 10\%$ ,  $V_{SS} = -20\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$ , and  $-55^{\circ}\text{C} \leq T_A \leq +210^{\circ}\text{C}$ , unless otherwise noted.

**Table 2.**

| Parameter                                  | Symbol <sup>1</sup>                 | Test Conditions/Comments <sup>1</sup>                                                                                                          | Min      | Typ <sup>2</sup> | Max      | Unit          |
|--------------------------------------------|-------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------|----------|------------------|----------|---------------|
| <b>ANALOG SWITCH</b>                       |                                     |                                                                                                                                                |          |                  |          |               |
| Analog Signal Range                        |                                     |                                                                                                                                                | $V_{SS}$ |                  | $V_{DD}$ | V             |
| On Resistance                              | $R_{ON}$                            | $V_S = \pm 15\text{ V}$ , $I_{DS} = -1\text{ mA}$ , see Figure 31;<br>for maximum $R_{ON}$ , $V_{DD} = +18\text{ V}$ , $V_{SS} = -18\text{ V}$ |          | 240              | 350      | $\Omega$      |
| On-Resistance Match Between Channels       | $\Delta R_{ON}$                     | $V_S = \pm 15\text{ V}$ , $I_{DS} = -1\text{ mA}$                                                                                              |          | 1.5              | 10       | $\Omega$      |
| On-Resistance Flatness                     | $R_{FLAT(ON)}$                      | $V_S = \pm 15\text{ V}$ , $I_{DS} = -1\text{ mA}$                                                                                              |          | 55               | 110      | $\Omega$      |
| <b>LEAKAGE CURRENTS</b>                    |                                     |                                                                                                                                                |          |                  |          |               |
| Source Off Leakage                         | $I_S(\text{off})$                   | $V_{DD} = +22\text{ V}$ , $V_{SS} = -22\text{ V}$<br>$V_S = \pm 15\text{ V}$ , $V_D = \mp 15\text{ V}$ , see Figure 32                         | -8       | $\pm 0.005$      | +8       | nA            |
| Drain Off Leakage                          | $I_D(\text{off})$                   | $V_S = \pm 15\text{ V}$ , $V_D = \mp 15\text{ V}$ , see Figure 32                                                                              | -60      | $\pm 0.005$      | +60      | nA            |
| Channel On Leakage                         | $I_D(\text{on})$ , $I_S(\text{on})$ | $V_S = V_D = \pm 15\text{ V}$ , see Figure 30                                                                                                  | -70      | $\pm 0.01$       | +70      | nA            |
| <b>DIGITAL INPUTS</b>                      |                                     |                                                                                                                                                |          |                  |          |               |
| Input High Voltage                         | $V_{INH}$                           |                                                                                                                                                | 2.0      |                  |          | V             |
| Input Low Voltage                          | $V_{INL}$                           |                                                                                                                                                |          |                  | 0.8      | V             |
| Input Current                              | $I_{INL}$ or $I_{INH}$              | $V_{IN} = V_{GND}$ or $V_{DD}$                                                                                                                 | -0.1     | +0.002           | +0.1     | $\mu\text{A}$ |
| Digital Input Capacitance                  | $C_{IN}$                            |                                                                                                                                                |          | 3                |          | pF            |
| <b>DYNAMIC CHARACTERISTICS<sup>3</sup></b> |                                     |                                                                                                                                                |          |                  |          |               |
| Transition Time                            | $t_{TRANSITION}$                    | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_S = 10\text{ V}$ , see Figure 36                                                               |          | 140              | 305      | ns            |
| On Time                                    | $t_{ON(EN)}$                        | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_S = 10\text{ V}$ , see Figure 38                                                               |          | 120              | 245      | ns            |
| Off Time                                   | $t_{OFF(EN)}$                       | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_S = 10\text{ V}$ , see Figure 38                                                               |          | 160              | 260      | ns            |
| Break-Before-Make Time Delay               | $t_D$                               | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_{S1} = V_{S2} = 10\text{ V}$ ,<br>see Figure 37                                                | 20       | 45               |          | ns            |
| Charge Injection                           | $Q_{INJ}$                           | $V_S = 0\text{ V}$ , $R_S = 0\ \Omega$ , $C_L = 1\text{ nF}$ , see Figure 39                                                                   |          | 0.4              |          | pC            |
| Off Isolation                              |                                     | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ , see Figure 34                                                                  |          | 86               |          | dB            |
| Channel to Channel Crosstalk               |                                     | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ , see Figure 33                                                                  |          | -80              |          | dB            |
| -3 dB Bandwidth                            |                                     | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , see Figure 35                                                                                       |          | 121              |          | MHz           |
| Source Capacitance, Off                    | $C_S(\text{off})$                   | $V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                                        |          | 2.8              |          | pF            |
| Drain Capacitance, Off                     | $C_D(\text{off})$                   | $V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                                        |          | 33               |          | pF            |
| Source/Drain Capacitance, On               | $C_D(\text{on})$ , $C_S(\text{on})$ | $V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                                        |          | 36               |          | pF            |
| <b>POWER REQUIREMENTS</b>                  |                                     |                                                                                                                                                |          |                  |          |               |
| Supply Current                             |                                     | $V_{DD} = +22\text{ V}$ , $V_{SS} = -22\text{ V}$                                                                                              |          |                  |          |               |
| Positive                                   | $I_{DD}$                            | Digital inputs = 0 V or 5 V, see Figure 28                                                                                                     |          | 60               | 120      | $\mu\text{A}$ |
| Negative                                   | $I_{SS}$                            | Digital inputs = 0 V or 5 V, see Figure 29                                                                                                     |          | 10               | 20       | $\mu\text{A}$ |
| Ground Current                             | $I_{GND}$                           | Digital inputs = 0 V or 5 V                                                                                                                    |          | 60               | 120      | $\mu\text{A}$ |
| Supply Range                               | $V_{DD}/V_{SS}$                     | $GND = 0\text{ V}$                                                                                                                             | $\pm 9$  |                  | $\pm 22$ | V             |

<sup>1</sup> See the Terminology section.

<sup>2</sup>  $T_A = 25^{\circ}\text{C}$ , except for the analog switch and power requirements values, where  $T_A = 210^{\circ}\text{C}$ .

<sup>3</sup> Guaranteed by design, not subject to production test.

**12 V SINGLE SUPPLY**

$V_{DD} = 12\text{ V} \pm 10\%$ ,  $V_{SS} = 0\text{ V}$ ,  $GND = 0\text{ V}$ , and  $-55^{\circ}\text{C} \leq T_A \leq +210^{\circ}\text{C}$ , unless otherwise noted.

**Table 3.**

| Parameter                                  | Symbol <sup>1</sup>                 | Test Conditions/Comments <sup>1</sup>                                                                                                                   | Min      | Typ <sup>2</sup> | Max      | Unit          |
|--------------------------------------------|-------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------|----------|------------------|----------|---------------|
| <b>ANALOG SWITCH</b>                       |                                     |                                                                                                                                                         |          |                  |          |               |
| Analog Signal Range                        |                                     |                                                                                                                                                         | $V_{SS}$ |                  | $V_{DD}$ | V             |
| On Resistance                              | $R_{ON}$                            | $V_S = 0\text{ V to }10\text{ V}$ , $I_{DS} = -1\text{ mA}$ , see Figure 31;<br>for maximum $R_{ON}$ , $V_{DD} = 10.8\text{ V}$ , $V_{SS} = 0\text{ V}$ |          | 650              | 800      | $\Omega$      |
| On-Resistance Match Between Channels       | $\Delta R_{ON}$                     | $V_S = 0\text{ V to }10\text{ V}$ , $I_{DS} = -1\text{ mA}$                                                                                             |          | 3                | 24       | $\Omega$      |
| On-Resistance Flatness                     | $R_{FLAT(ON)}$                      | $V_S = 0\text{ V to }10\text{ V}$ , $I_{DS} = -1\text{ mA}$                                                                                             |          | 240              | 380      | $\Omega$      |
| <b>LEAKAGE CURRENTS</b>                    |                                     |                                                                                                                                                         |          |                  |          |               |
| Source Off Leakage                         | $I_S(\text{off})$                   | $V_{DD} = 13.2\text{ V}$ , $V_{SS} = 0\text{ V}$<br>$V_S = 1\text{ V}/10\text{ V}$ , $V_D = 10\text{ V}/1\text{ V}$ , see Figure 32                     | -8       | $\pm 0.005$      | +8       | nA            |
| Drain Off Leakage                          | $I_D(\text{off})$                   | $V_S = 1\text{ V}/10\text{ V}$ , $V_D = 10\text{ V}/1\text{ V}$ , see Figure 32                                                                         | -60      | $\pm 0.005$      | +60      | nA            |
| Channel On Leakage                         | $I_D(\text{on})$ , $I_S(\text{on})$ | $V_S = V_D = 1\text{ V}/10\text{ V}$ , see Figure 30                                                                                                    | -70      | $\pm 0.01$       | +70      | nA            |
| <b>DIGITAL INPUTS</b>                      |                                     |                                                                                                                                                         |          |                  |          |               |
| Input High Voltage                         | $V_{INH}$                           |                                                                                                                                                         | 2.0      |                  |          | V             |
| Input Low Voltage                          | $V_{INL}$                           |                                                                                                                                                         |          |                  | 0.8      | V             |
| Input Current                              | $I_{INL}$ or $I_{INH}$              | $V_{IN} = V_{GND}$ or $V_{DD}$                                                                                                                          | -0.1     | +0.002           | +0.1     | $\mu\text{A}$ |
| Digital Input Capacitance                  | $C_{IN}$                            |                                                                                                                                                         |          | 3                |          | pF            |
| <b>DYNAMIC CHARACTERISTICS<sup>3</sup></b> |                                     |                                                                                                                                                         |          |                  |          |               |
| Transition Time                            | $t_{TRANSITION}$                    | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_S = 8\text{ V}$ , see Figure 36                                                                         |          | 200              | 490      | ns            |
| On Time                                    | $t_{ON(EN)}$                        | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_S = 8\text{ V}$ , see Figure 38                                                                         |          | 180              | 435      | ns            |
| Off Time                                   | $t_{OFF(EN)}$                       | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_S = 8\text{ V}$ , see Figure 38                                                                         |          | 165              | 305      | ns            |
| Break-Before-Make Time Delay               | $t_D$                               | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_{S1} = V_{S2} = 8\text{ V}$ ,<br>see Figure 37                                                          | 40       | 95               |          | ns            |
| Charge Injection                           | $Q_{INJ}$                           | $V_S = 6\text{ V}$ , $R_S = 0\ \Omega$ , $C_L = 1\text{ nF}$ , see Figure 39                                                                            |          | 0.2              |          | pC            |
| Off Isolation                              |                                     | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ , see Figure 34                                                                           |          | -86              |          | dB            |
| Channel to Channel Crosstalk               |                                     | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ , see Figure 33                                                                           |          | -80              |          | dB            |
| -3 dB Bandwidth                            |                                     | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , see Figure 35                                                                                                |          | 95               |          | MHz           |
| Source Capacitance, Off                    | $C_S(\text{off})$                   | $V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                                                                                 |          | 3.3              |          | pF            |
| Drain Capacitance, Off                     | $C_D(\text{off})$                   | $V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                                                                                 |          | 38               |          | pF            |
| Source/Drain Capacitance, On               | $C_D(\text{on})$ , $C_S(\text{on})$ | $V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                                                                                 |          | 41               |          | pF            |
| <b>POWER REQUIREMENTS</b>                  |                                     |                                                                                                                                                         |          |                  |          |               |
| Supply Current                             |                                     | $V_{DD} = 13.2\text{ V}$                                                                                                                                |          |                  |          |               |
| Positive                                   | $I_{DD}$                            | Digital inputs = 0 V or 5 V, see Figure 28                                                                                                              |          | 50               | 75       | $\mu\text{A}$ |
| Negative                                   | $I_{SS}$                            | Digital inputs = 0 V or 5 V, see Figure 29                                                                                                              |          | 7.5              | 15       | $\mu\text{A}$ |
| Ground Current                             | $I_{GND}$                           | Digital inputs = 0 V or 5 V                                                                                                                             |          | 50               | 75       | $\mu\text{A}$ |
| Supply Range                               | $V_{DD}/V_{SS}$                     | $GND = 0\text{ V}$ , $V_{SS} = 0\text{ V}$                                                                                                              | 9        |                  | 40       | V             |

<sup>1</sup> See the Terminology section.

<sup>2</sup>  $T_A = 25^{\circ}\text{C}$ , except for the analog switch and power requirements values, where  $T_A = 210^{\circ}\text{C}$ .

<sup>3</sup> Guaranteed by design, not subject to production test.

**36 V SINGLE SUPPLY**

$V_{DD} = 36\text{ V} \pm 10\%$ ,  $V_{SS} = 0\text{ V}$ ,  $GND = 0\text{ V}$ , and  $-55^{\circ}\text{C} \leq T_A \leq +210^{\circ}\text{C}$ , unless otherwise noted.

**Table 4.**

| Parameter                                  | Symbol <sup>1</sup>                 | Test Conditions/ Comments <sup>1</sup>                                                                                                                  | Min      | Typ <sup>2</sup> | Max      | Unit          |
|--------------------------------------------|-------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------|----------|------------------|----------|---------------|
| <b>ANALOG SWITCH</b>                       |                                     |                                                                                                                                                         |          |                  |          |               |
| Analog Signal Range                        |                                     |                                                                                                                                                         | $V_{SS}$ |                  | $V_{DD}$ | V             |
| On Resistance                              | $R_{ON}$                            | $V_S = 0\text{ V to }30\text{ V}$ , $I_{DS} = -1\text{ mA}$ , see Figure 31;<br>for maximum $R_{ON}$ , $V_{DD} = 32.4\text{ V}$ , $V_{SS} = 0\text{ V}$ |          | 260              | 350      | $\Omega$      |
| On-Resistance Match Between Channels       | $\Delta R_{ON}$                     | $V_S = 0\text{ V to }30\text{ V}$ , $I_{DS} = -1\text{ mA}$                                                                                             |          | 1.5              | 10       | $\Omega$      |
| On-Resistance Flatness                     | $R_{FLAT(ON)}$                      | $V_S = 0\text{ V to }30\text{ V}$ , $I_{DS} = -1\text{ mA}$                                                                                             |          | 55               | 110      | $\Omega$      |
| <b>LEAKAGE CURRENTS</b>                    |                                     |                                                                                                                                                         |          |                  |          |               |
| Source Off Leakage                         | $I_S(\text{off})$                   | $V_{DD} = 13.2\text{ V}$ , $V_{SS} = 0\text{ V}$<br>$V_S = 1\text{ V}/10\text{ V}$ , $V_D = 10\text{ V}/1\text{ V}$ , see Figure 32                     | -8       | $\pm 0.005$      | +8       | nA            |
| Drain Off Leakage                          | $I_D(\text{off})$                   | $V_S = 1\text{ V}/10\text{ V}$ , $V_D = 10\text{ V}/1\text{ V}$ , see Figure 32                                                                         | -60      | $\pm 0.005$      | +60      | nA            |
| Channel On Leakage                         | $I_D(\text{on})$ , $I_S(\text{on})$ | $V_S = V_D = 1\text{ V}/10\text{ V}$ , see Figure 30                                                                                                    | -70      | $\pm 0.01$       | +70      | nA            |
| <b>DIGITAL INPUTS</b>                      |                                     |                                                                                                                                                         |          |                  |          |               |
| Input High Voltage                         | $V_{INH}$                           |                                                                                                                                                         | 2.0      |                  |          | V             |
| Input Low Voltage                          | $V_{INL}$                           |                                                                                                                                                         |          |                  | 0.8      | V             |
| Input Current                              | $I_{INL}$ or $I_{INH}$              | $V_{IN} = V_{GND}$ or $V_{DD}$                                                                                                                          | -0.1     | +0.002           | +0.1     | $\mu\text{A}$ |
| Digital Input Capacitance                  | $C_{IN}$                            |                                                                                                                                                         |          | 3                |          | pF            |
| <b>DYNAMIC CHARACTERISTICS<sup>3</sup></b> |                                     |                                                                                                                                                         |          |                  |          |               |
| Transition Time                            | $t_{TRANSITION}$                    | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_S = 18\text{ V}$ , see Figure 36                                                                        |          | 170              | 320      | ns            |
| On Time                                    | $t_{ON(EN)}$                        | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_S = 18\text{ V}$ , see Figure 38                                                                        |          | 150              | 265      | ns            |
| Off Time                                   | $t_{OFF(EN)}$                       | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_S = 18\text{ V}$ , see Figure 38                                                                        |          | 180              | 265      | ns            |
| Break-Before-Make Time Delay               | $t_D$                               | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ , $V_{S1} = V_{S2} = 18\text{ V}$ ,<br>see Figure 37                                                         | 20       | 55               |          | ns            |
| Charge Injection                           | $Q_{INJ}$                           | $V_S = 6\text{ V}$ , $R_S = 0\ \Omega$ , $C_L = 1\text{ nF}$ , see Figure 39                                                                            |          | 0.3              |          | pC            |
| Off Isolation                              |                                     | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ , see Figure 34                                                                           |          | -86              |          | dB            |
| Channel to Channel Crosstalk               |                                     | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ , see Figure 33                                                                           |          | -80              |          | dB            |
| -3 dB Bandwidth                            |                                     | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , see Figure 35                                                                                                |          | 105              |          | MHz           |
| Source Capacitance, Off                    | $C_S(\text{off})$                   | $V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                                                                                 |          | 2.7              |          | pF            |
| Drain Capacitance, Off                     | $C_D(\text{off})$                   | $V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                                                                                 |          | 32               |          | pF            |
| Source/Drain Capacitance, On               | $C_D(\text{on})$ , $C_S(\text{on})$ | $V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                                                                                 |          | 35               |          | pF            |
| <b>POWER REQUIREMENTS</b>                  |                                     |                                                                                                                                                         |          |                  |          |               |
| Supply Current                             |                                     | $V_{DD} = 13.2\text{ V}$                                                                                                                                |          |                  |          |               |
| Positive                                   | $I_{DD}$                            | Digital inputs = 0 V or 5 V, see Figure 28                                                                                                              |          | 80               | 155      | $\mu\text{A}$ |
| Negative                                   | $I_{SS}$                            | Digital inputs = 0 V or 5 V, see Figure 29                                                                                                              |          | 10               | 20       | $\mu\text{A}$ |
| Ground Current                             | $I_{GND}$                           | Digital inputs = 0 V or 5 V                                                                                                                             |          | 80               | 155      | $\mu\text{A}$ |
| Supply Range                               | $V_{DD}/V_{SS}$                     | $GND = 0\text{ V}$ , $V_{SS} = 0\text{ V}$                                                                                                              | 9        |                  | 40       | V             |

<sup>1</sup> See the Terminology section.

<sup>2</sup>  $T_A = 25^{\circ}\text{C}$ , except for the analog switch and power requirements values, where  $T_A = 210^{\circ}\text{C}$ .

<sup>3</sup> Guaranteed by design, not subject to production test.

**CONTINUOUS CURRENT PER CHANNEL (Sx OR D)****Table 5.**

| Parameter                                         | Test Conditions/Comments             | 175°C | 210°C | Unit       |
|---------------------------------------------------|--------------------------------------|-------|-------|------------|
| <b>CONTINUOUS CURRENT (Sx OR D)</b>               |                                      |       |       |            |
| $V_{DD} = +15\text{ V}$ , $V_{SS} = -15\text{ V}$ | $\theta_{JA} = 70^{\circ}\text{C/W}$ | 10    | 10    | mA maximum |
| $V_{DD} = +20\text{ V}$ , $V_{SS} = -20\text{ V}$ |                                      | 10    | 10    | mA maximum |
| $V_{DD} = 12\text{ V}$ , $V_{SS} = 0\text{ V}$    |                                      | 6     | 6     | mA maximum |
| $V_{DD} = 36\text{ V}$ , $V_{SS} = 0\text{ V}$    |                                      | 10    | 10    | mA maximum |

## ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 6.**

| Parameter                                     | Rating                                                                                 |
|-----------------------------------------------|----------------------------------------------------------------------------------------|
| $V_{DD}$ to $V_{SS}$                          | 48 V                                                                                   |
| $V_{DD}$ to GND                               | −0.3 V to +48 V                                                                        |
| $V_{SS}$ to GND                               | +0.3 V to −48 V                                                                        |
| Analog Inputs <sup>1</sup>                    | $V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$ or<br>30 mA, whichever occurs first |
| Digital Inputs <sup>1</sup>                   | $V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$ or<br>30 mA, whichever occurs first |
| Peak Current, Sx or D Pins                    | 31 mA (pulsed at 1 ms, 10%<br>duty cycle maximum)                                      |
| Continuous Current, Sx or D Pins <sup>2</sup> | Data + 5%                                                                              |
| Temperature Range                             | −55°C to +120°C                                                                        |
| Junction Temperature                          | 212°C                                                                                  |
| Reflow Soldering Peak Temperature,<br>Pb Free | 260°C (+ 0°C/− 5°C)                                                                    |

<sup>1</sup> Overvoltages at the Ax, EN, Sx, or D pins are clamped by internal diodes.  
Limit the current to the maximum ratings given.

<sup>2</sup> See Table 5.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Only one absolute maximum rating can be applied at any one time.

## THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

**Table 7. Thermal Resistance**

| Package Type         | $\theta_{JA}$ | $\theta_{JC}$ | Unit |
|----------------------|---------------|---------------|------|
| F-16-1 <sup>1</sup>  | 70            | 22            | °C/W |
| FR-16-1 <sup>1</sup> | 70            | 10            | °C/W |

<sup>1</sup> Thermal impedance simulated values are based on JEDEC 2s2p thermal test board. See JEDEC JESD51.

## ESD CAUTION



**ESD (electrostatic discharge) sensitive device.**  
Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

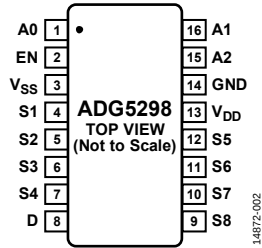


Figure 2. FLATPACK Pin Configuration

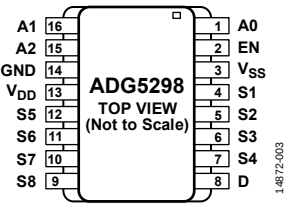


Figure 3. Reversed Formed FLATPACK Pin Configuration

Table 8. Pin Function Descriptions

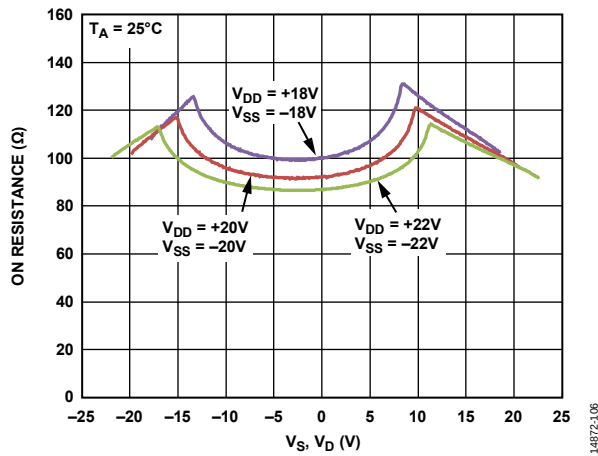
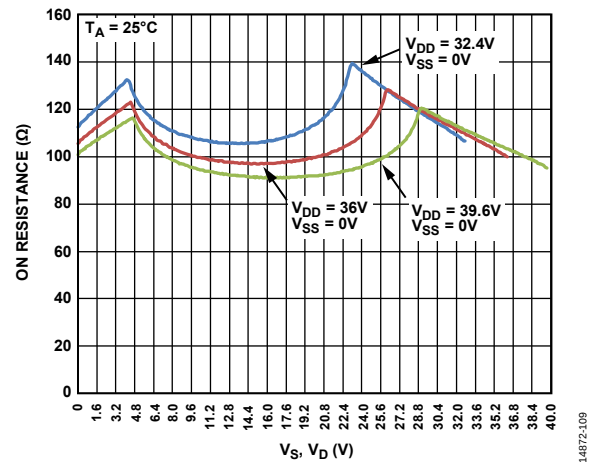
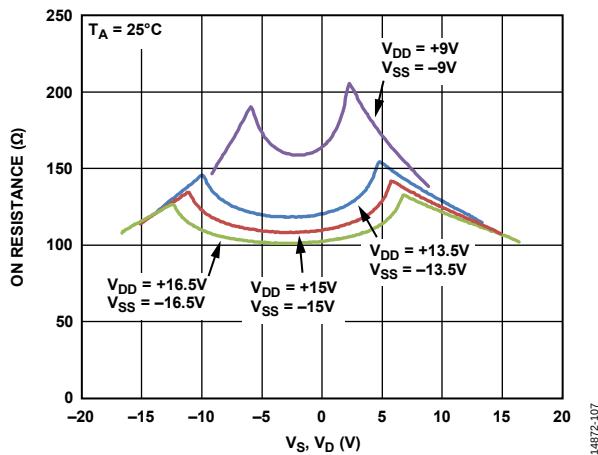
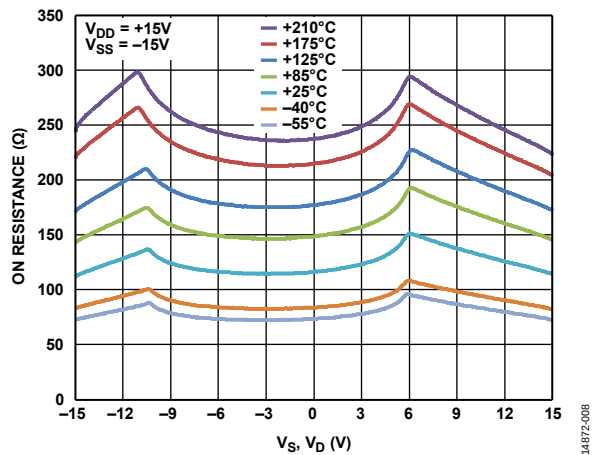
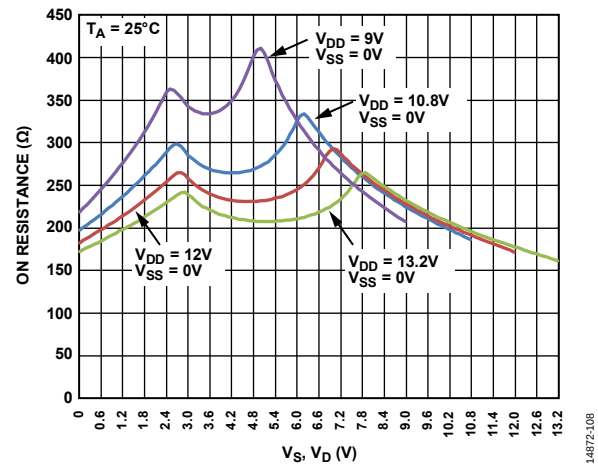
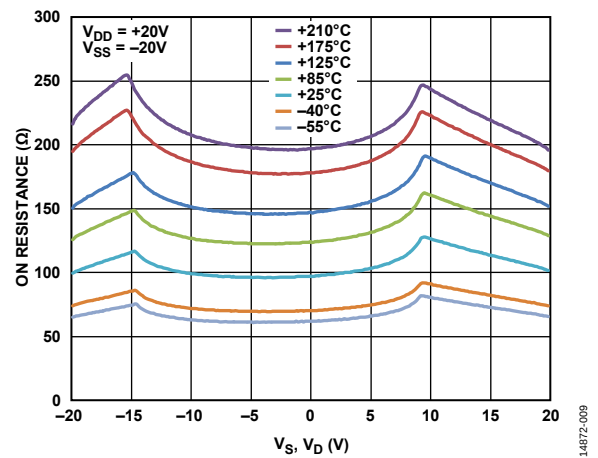
| Pin No. | Mnemonic        | Description                                                                                                                                     |
|---------|-----------------|-------------------------------------------------------------------------------------------------------------------------------------------------|
| 1       | A0              | Logic Control Input 0.                                                                                                                          |
| 2       | EN              | Active High Digital Input. When low, the device is disabled and all switches are off. When high, the Ax logic inputs determine the on switches. |
| 3       | V <sub>SS</sub> | Most Negative Power Supply Potential. In single-supply applications, this pin can be connected to ground.                                       |
| 4       | S1              | Source Terminal 1. This pin can be an input or an output.                                                                                       |
| 5       | S2              | Source Terminal 2. This pin can be an input or an output.                                                                                       |
| 6       | S3              | Source Terminal 3. This pin can be an input or an output.                                                                                       |
| 7       | S4              | Source Terminal 4. This pin can be an input or an output.                                                                                       |
| 8       | D               | Drain Terminal. This pin can be an input or an output.                                                                                          |
| 9       | S8              | Source Terminal 8. This pin can be an input or an output.                                                                                       |
| 10      | S7              | Source Terminal 7. This pin can be an input or an output.                                                                                       |
| 11      | S6              | Source Terminal 6. This pin can be an input or an output.                                                                                       |
| 12      | S5              | Source Terminal 5. This pin can be an input or an output.                                                                                       |
| 13      | V <sub>DD</sub> | Most Positive Power Supply Potential.                                                                                                           |
| 14      | GND             | Ground (0 V) Reference.                                                                                                                         |
| 15      | A2              | Logic Control Input 2.                                                                                                                          |
| 16      | A1              | Logic Control Input 1.                                                                                                                          |

Table 9. Truth Table

| A2             | A1             | A0             | EN | On Switch |
|----------------|----------------|----------------|----|-----------|
| X <sup>1</sup> | X <sup>1</sup> | X <sup>1</sup> | 0  | None      |
| 0              | 0              | 0              | 1  | S1        |
| 0              | 0              | 1              | 1  | S2        |
| 0              | 1              | 0              | 1  | S3        |
| 0              | 1              | 1              | 1  | S4        |
| 1              | 0              | 0              | 1  | S5        |
| 1              | 0              | 1              | 1  | S6        |
| 1              | 1              | 0              | 1  | S7        |
| 1              | 1              | 1              | 1  | S8        |

<sup>1</sup> X is don't care.

## TYPICAL PERFORMANCE CHARACTERISTICS

Figure 4. On Resistance ( $R_{ON}$ ) as a Function of  $V_S, V_D$  ( $\pm 20$  V Dual Supply)Figure 7. On Resistance ( $R_{ON}$ ) as a Function of  $V_S, V_D$  (36 V Single Supply)Figure 5. On Resistance ( $R_{ON}$ ) as a Function of  $V_S, V_D$  ( $\pm 15$  V Dual Supply)Figure 8. On Resistance ( $R_{ON}$ ) as a Function of  $V_S, V_D$  for Various Temperatures,  $\pm 15$  V Dual SupplyFigure 6. On Resistance ( $R_{ON}$ ) as a Function of  $V_S, V_D$  (12 V Single Supply)Figure 9. On Resistance ( $R_{ON}$ ) as a Function of  $V_S, V_D$  for Various Temperatures,  $\pm 20$  V Dual Supply

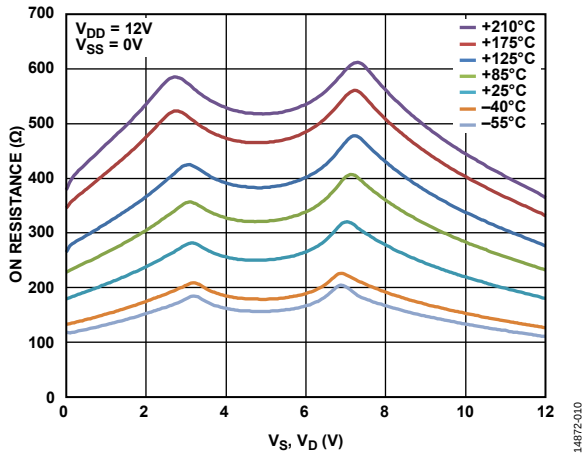


Figure 10. On Resistance ( $R_{ON}$ ) as a Function of  $V_S, V_D$  for Various Temperatures, 12 V Single Supply

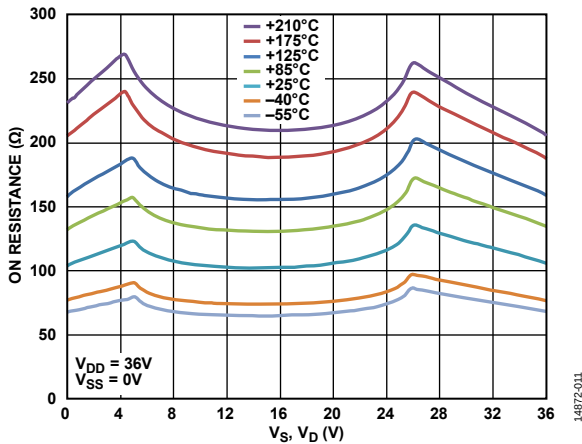


Figure 11. On Resistance ( $R_{ON}$ ) as a Function of  $V_S, V_D$  for Various Temperatures, 36 V Single Supply

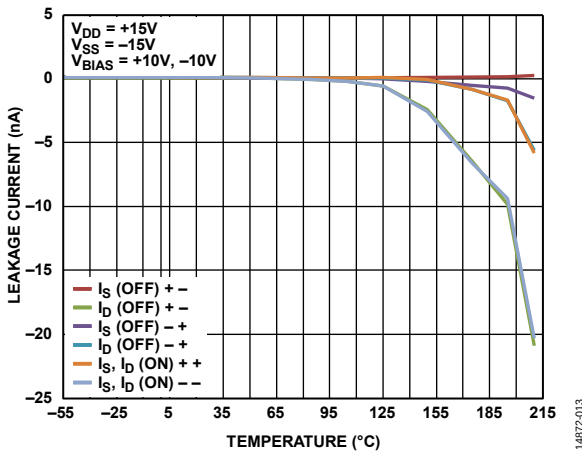


Figure 12. Leakage Currents vs. Temperature,  $\pm 15$  V Dual Supply

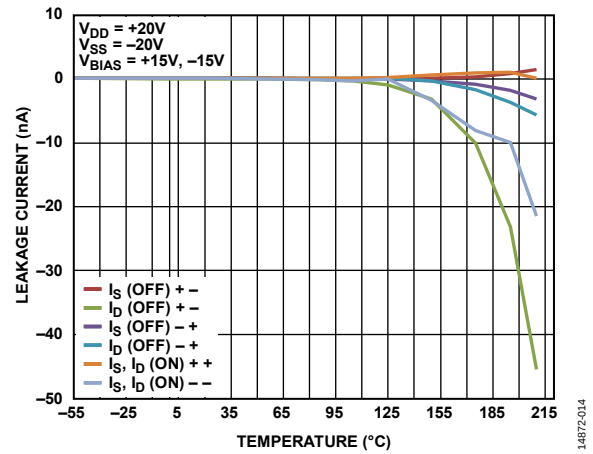


Figure 13. Leakage Current vs. Temperature,  $\pm 20$  V Dual Supply

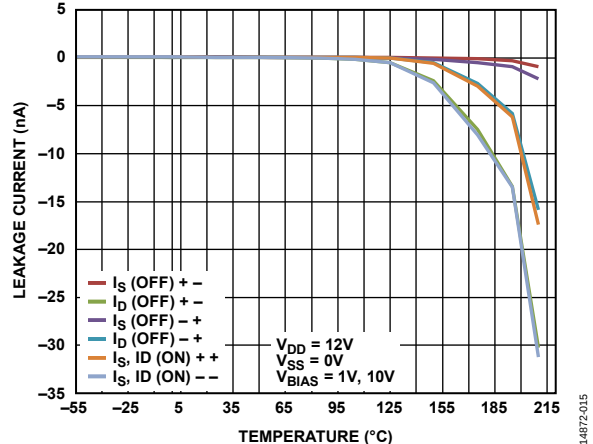


Figure 14. Leakage Current vs. Temperature, 12 V Single Supply

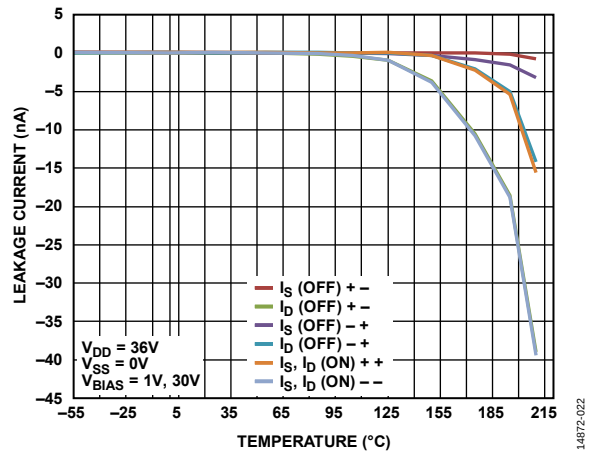
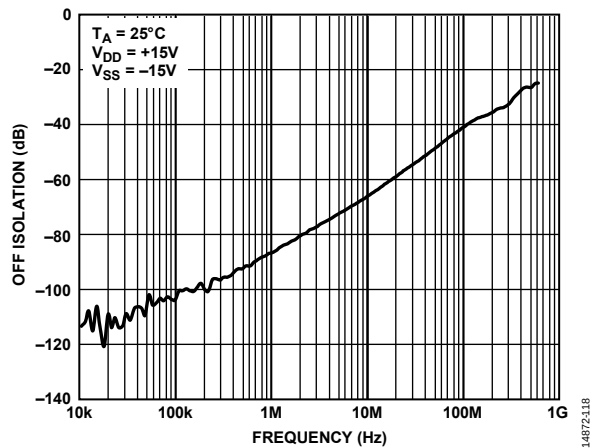
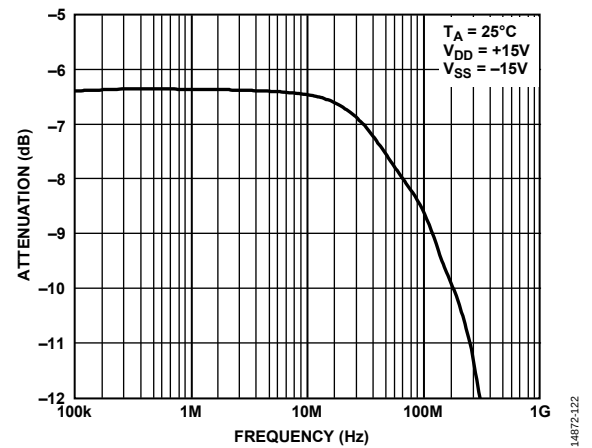
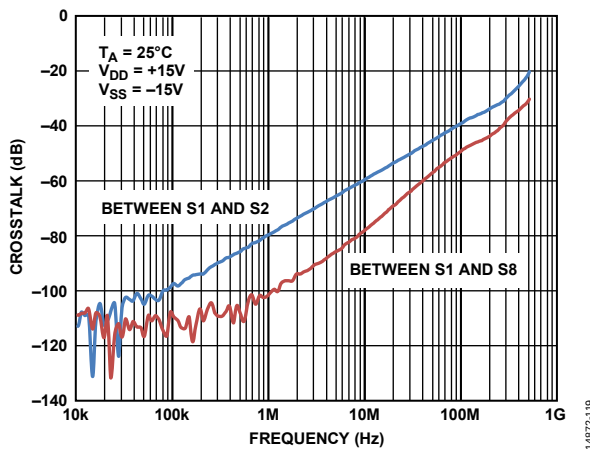
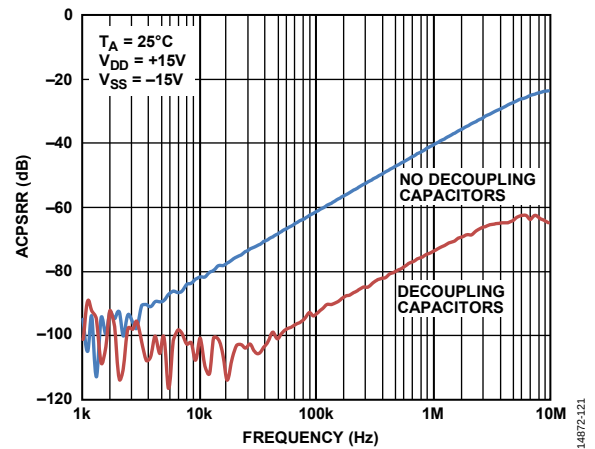
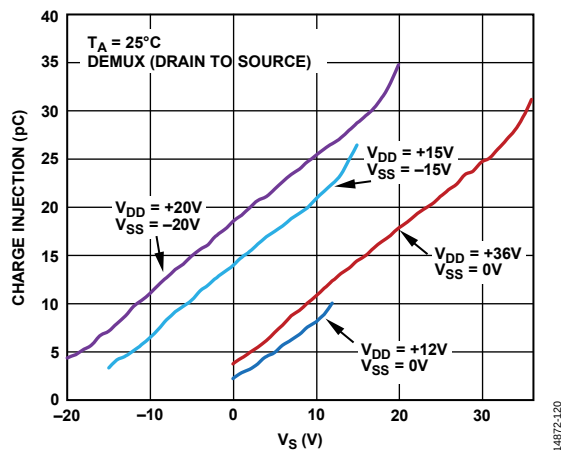
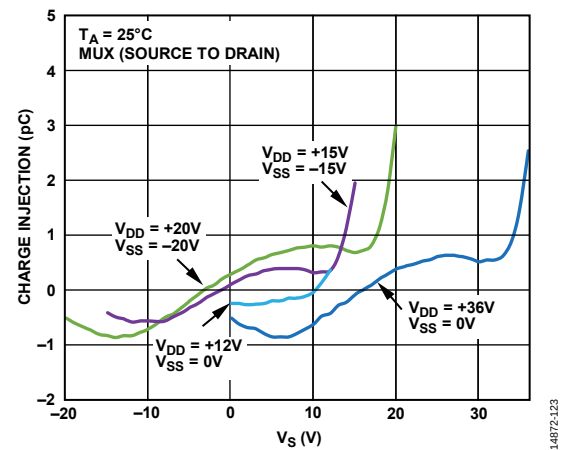


Figure 15. Leakage Current vs. Temperature, 36 V Single Supply

Figure 16. Off Isolation vs. Frequency,  $\pm 15$  V Dual SupplyFigure 19. Attenuation vs. Frequency,  $\pm 15$  V Dual SupplyFigure 17. Crosstalk vs. Frequency,  $\pm 15$  V Dual SupplyFigure 20. ACPSRR vs. Frequency,  $\pm 15$  V Dual SupplyFigure 18. Charge Injection ( $Q_{INJ}$ ) vs. Source Voltage ( $V_S$ ), Drain to SourceFigure 21. Charge Injection ( $Q_{INJ}$ ) vs. Source Voltage ( $V_S$ ), Source to Drain

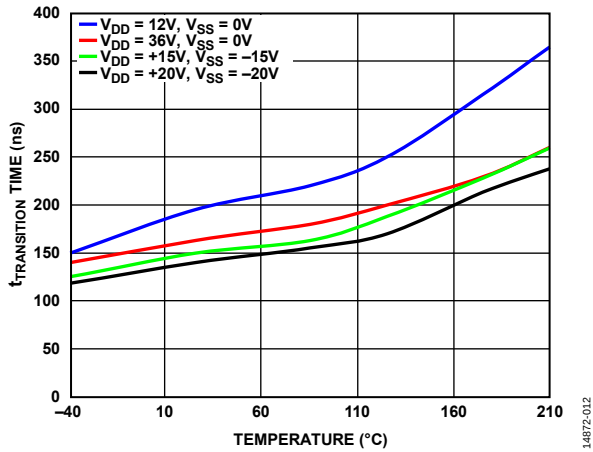


Figure 22.  $t_{\text{TRANSITION}}$  Time vs. Temperature

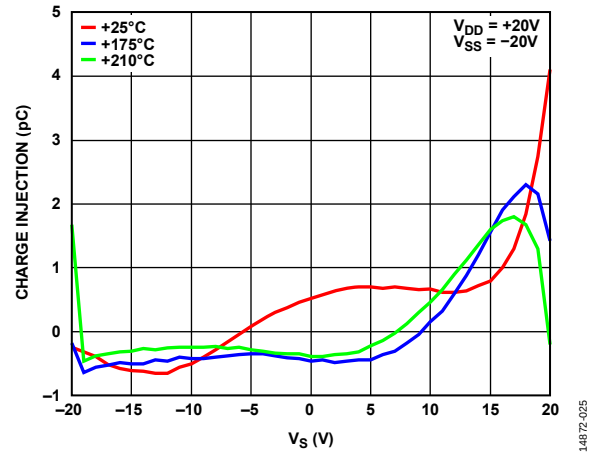


Figure 25. Charge Injection as a Function of  $V_S$  for Various Temperatures,  $\pm 20$  V Dual Supply

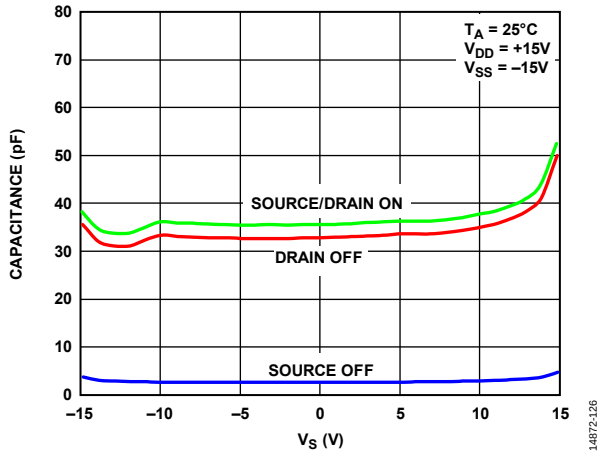


Figure 23. Capacitance vs. Source Voltage ( $V_S$ ),  $\pm 15$  V Dual Supply

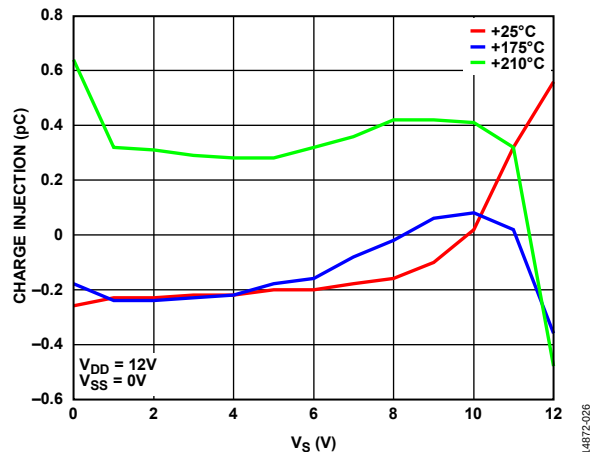


Figure 26. Charge Injection as a Function of  $V_S$  for Various Temperatures, 12 V Single Supply

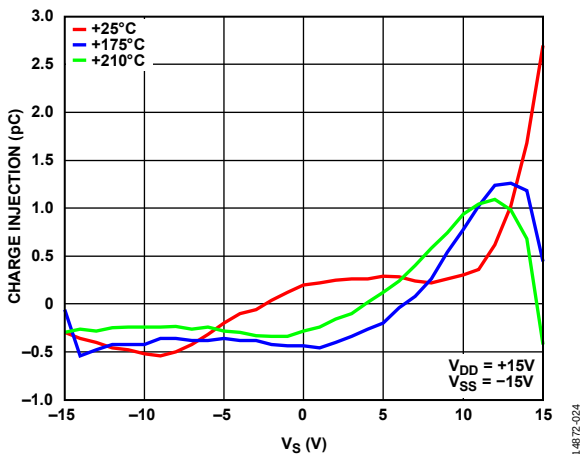


Figure 24. Charge Injection as a Function of  $V_S$  for Various Temperatures,  $\pm 15$  V Dual Supply

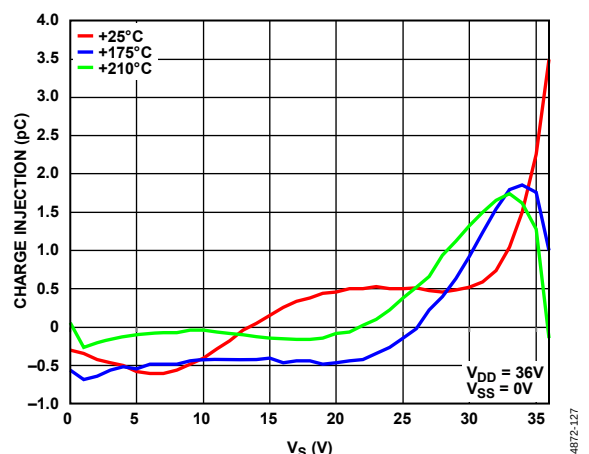
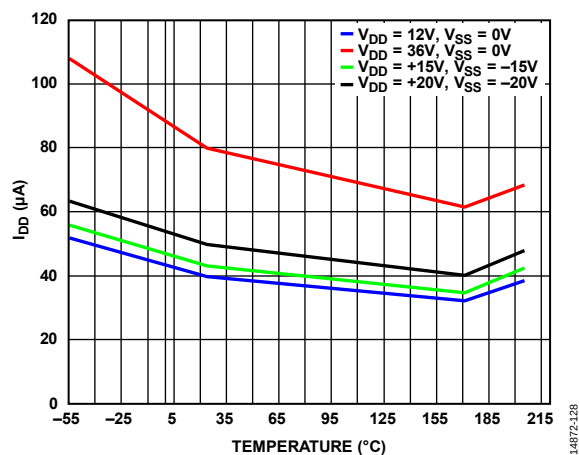
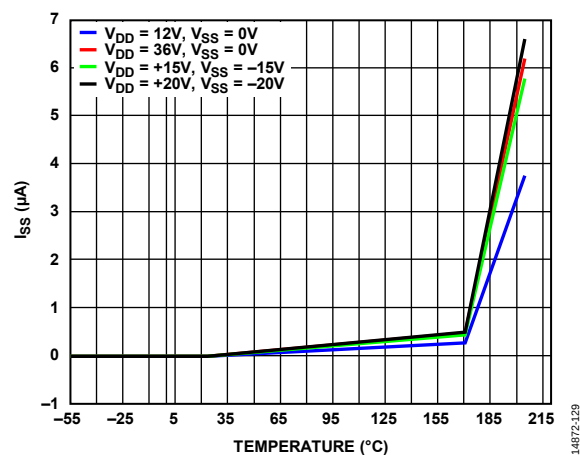


Figure 27. Charge Injection as a Function of  $V_S$  for Various Temperatures, 36 V Single Supply

Figure 28.  $I_{DD}$  vs TemperatureFigure 29.  $I_{SS}$  vs Temperature

## TEST CIRCUITS

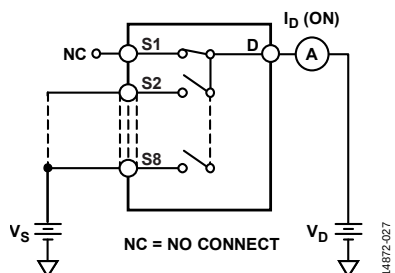


Figure 30. On Leakage

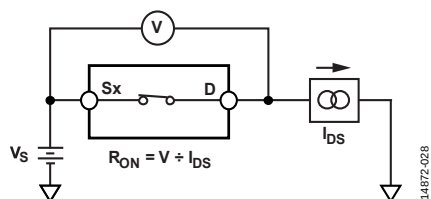


Figure 31. On Resistance

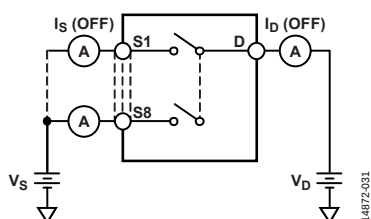


Figure 32. Off Leakage

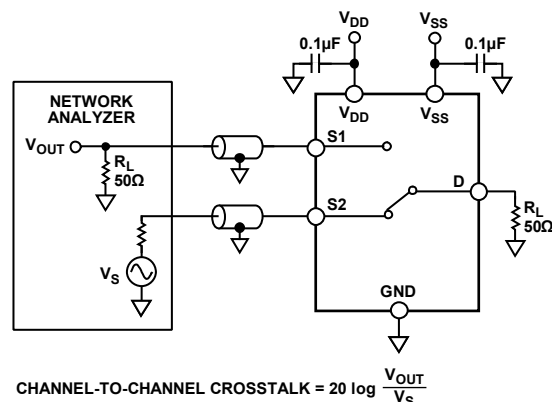


Figure 33. Channel-to-Channel Crosstalk

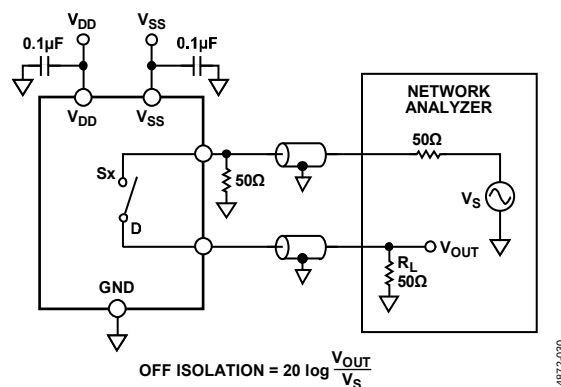


Figure 34. Off Isolation

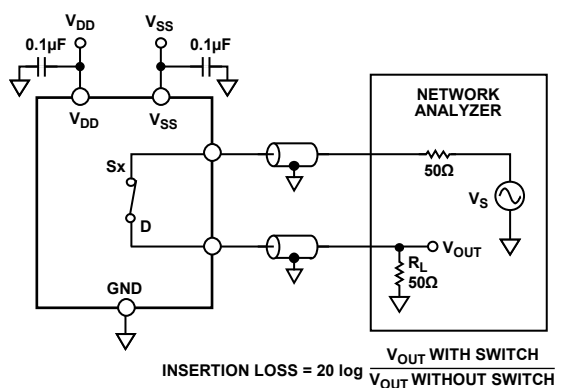
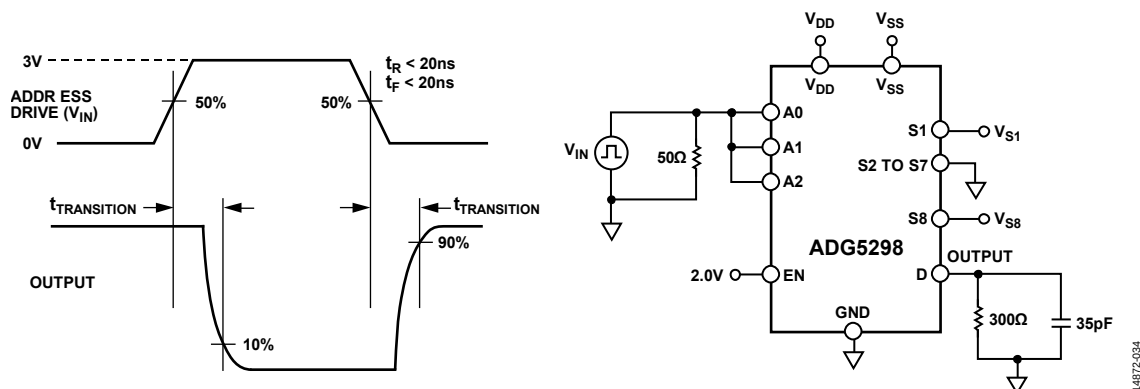
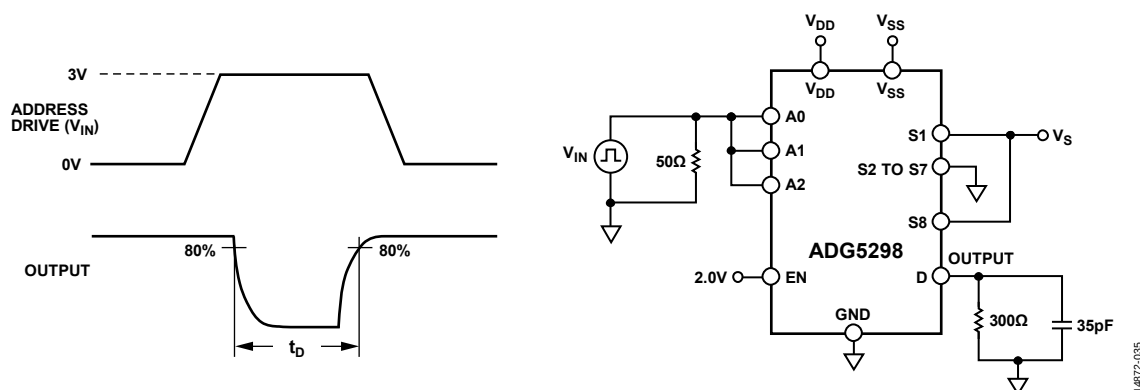
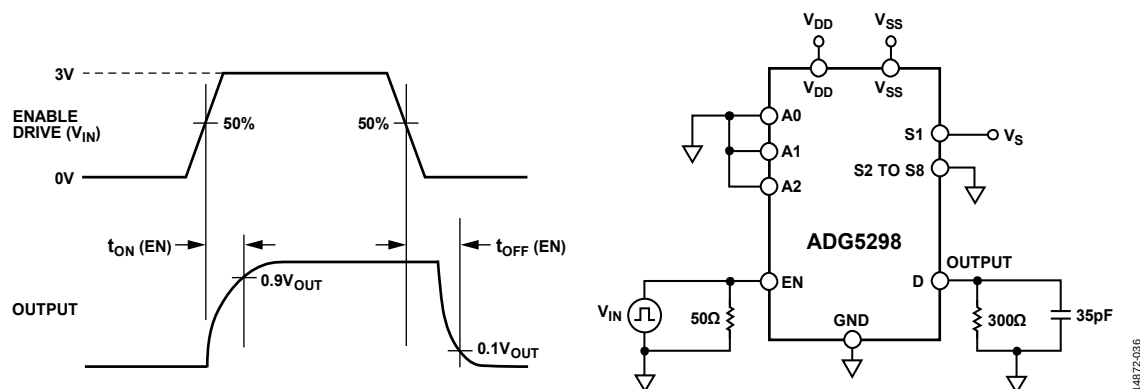
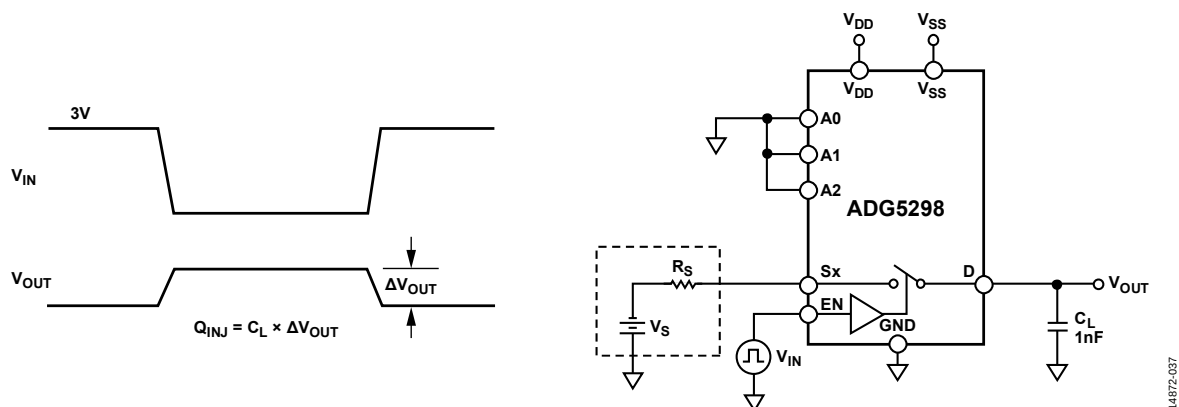


Figure 35. -3 dB Bandwidth

Figure 36. Address to Output Switching Times,  $t_{\text{TRANSITION}}$ Figure 37. Break-Before-Make Time Delay,  $t_D$ Figure 38. Enable Delay,  $t_{\text{ON}}(\text{EN})$ ,  $t_{\text{OFF}}(\text{EN})$ Figure 39. Charge Injection,  $Q_{\text{INJ}}$

## TERMINOLOGY

### **$I_{DD}$**

$I_{DD}$  represents the positive supply current.

### **$I_{SS}$**

$I_{SS}$  represents the negative supply current.

### **$V_D, V_S$**

$V_D$  and  $V_S$  represent the analog voltage on Terminal D and Terminal Sx, respectively.

### **$R_{ON}$**

$R_{ON}$  is the ohmic resistance between Terminal D and Terminal Sx.

### **$\Delta R_{ON}$**

$\Delta R_{ON}$  represents the difference between the  $R_{ON}$  of any two channels.

### **$R_{FLAT (ON)}$**

Flatness that is defined as the difference between the maximum and minimum value of on resistance measured over the specified analog signal range is represented by  $R_{FLAT (ON)}$ .

### **$I_S (Off)$**

$I_S (off)$  is the source leakage current with the switch off.

### **$I_D (Off)$**

$I_D (off)$  is the drain leakage current with the switch off.

### **$I_D (On), I_S (On)$**

$I_D (on)$  and  $I_S (on)$  represent the channel leakage currents with the switch on.

### **$V_{INL}$**

$V_{INL}$  is the maximum input voltage for Logic 0.

### **$V_{INH}$**

$V_{INH}$  is the minimum input voltage for Logic 1.

### **$I_{INL}, I_{INH}$**

$I_{INL}$  and  $I_{INH}$  represent the low and high input currents of the digital inputs.

### **$C_D (Off)$**

$C_D (off)$  represents the off switch drain capacitance, which is measured with reference to ground.

### **$C_S (Off)$**

$C_S (off)$  represents the off switch source capacitance, which is measured with reference to ground.

### **$C_D (On), C_S (On)$**

$C_D (on)$  and  $C_S (on)$  represent on switch capacitances, which are measured with reference to ground.

### **$C_{IN}$**

$C_{IN}$  represents the digital input capacitance.

### **$t_{ON (EN)}$**

$t_{ON (EN)}$  represents the delay time between the 50% and 90% points of the digital input and switch on condition.

### **$t_{OFF (EN)}$**

$t_{OFF (EN)}$  represents the delay time between the 50% and 90% points of the digital input and switch off condition.

### **$t_{TRANSITION}$**

$t_{TRANSITION}$  represents the delay time between the 50% and 90% points of the digital inputs and the switch on condition when switching from one address state to another.

### **Break-Before-Make Time Delay ( $t_D$ )**

$t_D$  represents the off time measured between the 80% point of both switches when switching from one address state to another.

### **Off Isolation**

Off isolation is a measure of unwanted signal coupling through an off channel.

### **Charge Injection**

Charge injection is a measure of the glitch impulse transferred from the digital input to the analog output during switching.

### **Crosstalk**

Crosstalk is a measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

### **Bandwidth**

Bandwidth is the frequency at which the output is attenuated by -3 dB.

### **On Response**

On response is the frequency response of the on switch.

### **AC Power Supply Rejection Ratio (ACPSRR)**

ACPSRR is a measure of the ability of a device to avoid coupling noise and spurious signals that appear on the supply voltage pin to the output of the switch. The dc voltage on the device is modulated by a sine wave of 0.62 V p-p. The ratio of the amplitude of signal on the output to the amplitude of the modulation is the ACPSRR.

## THEORY OF OPERATION

The [ADG5298](#) is a latch-up proof, bidirectional, 8:1 CMOS multiplexer that is designed to operate at very high temperatures. The device is controlled by four parallel digital inputs (EN, A0, A1, and A2). The EN input allows for the [ADG5298](#) to be enabled or disabled. When the [ADG5298](#) is disabled, the source pins (S1 to S8) disconnect from the drain pin (D). When the [ADG5298](#) is enabled, the address lines (A0, A1, and A2) can determine which source pin (S1 to S8) is connected to the drain pin (D).

### TRENCH ISOLATION

In the [ADG5298](#), an insulating oxide layer (trench) is placed between the negative channel metal-oxide semiconductor (NMOS) and the positive channel metal-oxide semiconductor (PMOS) transistors of each CMOS switch. Parasitic junctions, which occur between the transistors in junction isolated switches, are eliminated, and the result is a completely latch-up proof switch that has minimal leakage over temperature.

In junction isolation, the N well and P well of the PMOS and NMOS transistors form a diode that is reverse biased under normal operation. However, during overvoltage conditions, this diode can become forward-biased. A silicon controlled rectifier (SCR) type circuit is formed by the two transistors, causing a significant amplification of the current that, in turn, leads to latch-up. With trench isolation, this diode is removed, and the result is a latch-up proof switch.

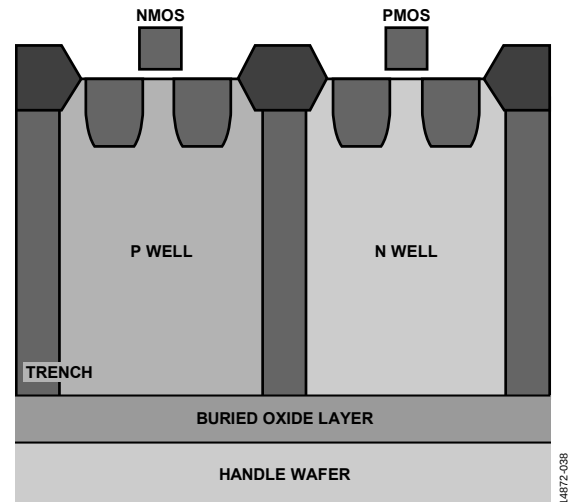


Figure 40. Trench Isolation

## APPLICATIONS INFORMATION

The ultralow capacitance and charge injection of this switch makes it an ideal solution for data acquisition and sample-and-hold applications, where low glitch and fast settling are required.

The [ADG5298](#) can operate in a wide ambient temperature range from  $-55^{\circ}\text{C}$  to  $+210^{\circ}\text{C}$ . Its wide range coupled with its

latch-up immune and low leakage features makes the [ADG5298](#) perfect for use in harsh environments, such as downhole drilling and avionics. The [ADG5298](#) has achieved a JESD78D Class II rating, handling stresses to  $\pm 500\text{ mA}$  with a 10 ms pulse at the maximum operating temperature of the device ( $210^{\circ}\text{C}$ ).

## OUTLINE DIMENSIONS

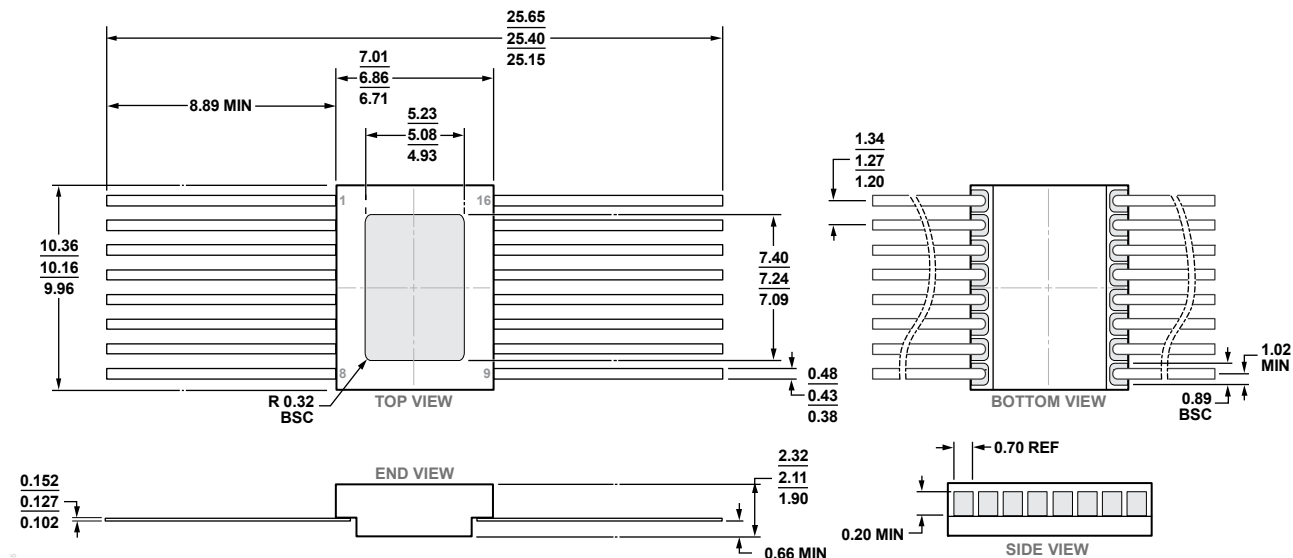


Figure 41. 16-Lead Ceramic Flat Package [FLATPACK]  
(F-16-1)  
Dimensions shown in millimeters

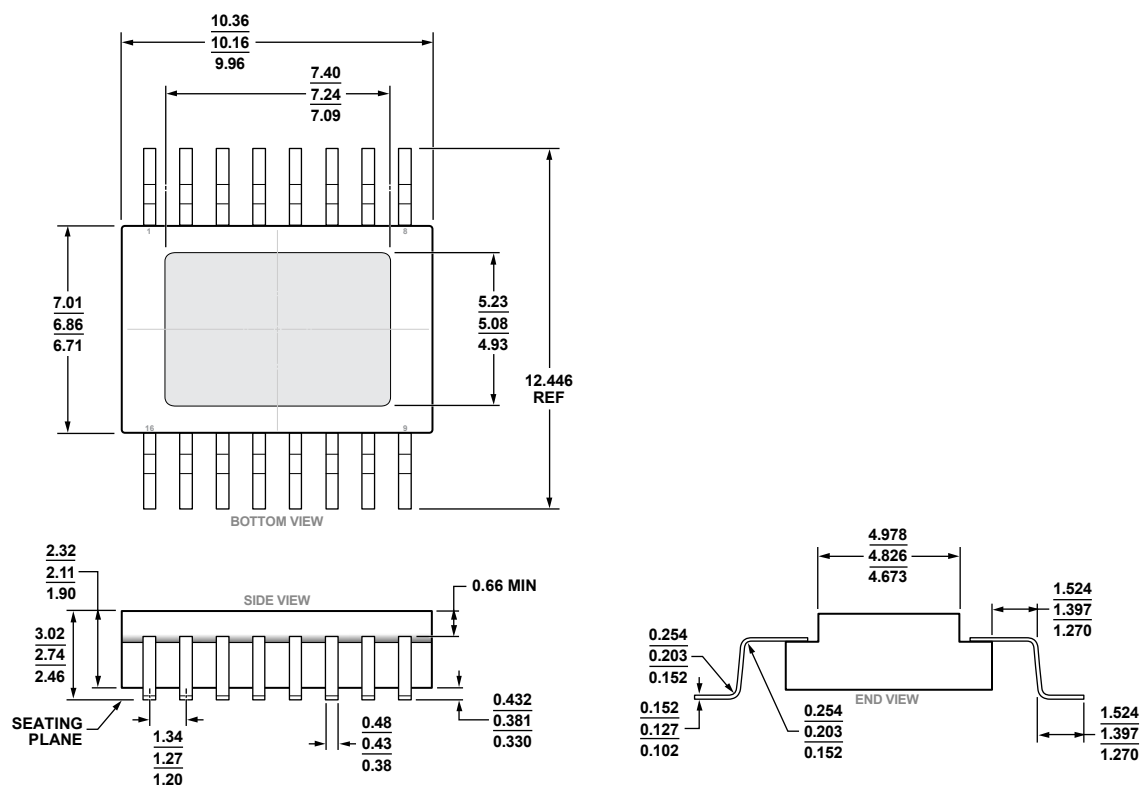


Figure 42. 16-Lead Ceramic Flat Package with Reverse Formed Gullwing Leads [FLATPACK\_RF]  
Cavity Down  
(FR-16-1)  
Dimensions shown in millimeters

## ORDERING GUIDE

| Model <sup>1</sup> | Temperature Range | Package Description                                                           | Package Option |
|--------------------|-------------------|-------------------------------------------------------------------------------|----------------|
| ADG5298HFZ         | –55°C to +210°C   | 16-Lead Ceramic Flat Package [FLATPACK]                                       | F-16-1         |
| ADG5298HFRZ        | –55°C to +210°C   | 16-Lead Ceramic Flat Package with Reverse Formed Gullwing Leads [FLATPACK_RF] | FR-16-1        |
| EVAL-ADG5298EB1Z   |                   | Evaluation Board                                                              |                |

<sup>1</sup> Z = RoHS Compliant Part.